

80V NPN DARLINGTON TRANSISTOR IN SOT23

Features

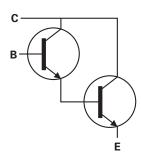
- BV_{CES} > 80V
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- High Current Gain
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

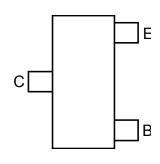
- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>3
- Weight 0.008 grams (approximate)







Device Symbol



Top View Pin-Out

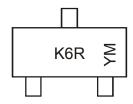
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBTA28-7-F	AEC-Q101	K6R	7	8	3,000
MMBTA28-13-F	AEC-Q101	K6R	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K6R = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: B = 2014) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

	Year	2010		2011	2012		2013	2014		2015	2016	i	2017
	Code	Х		Υ	Z		Α	В		С	D		Е
1	Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
	Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CES}	80	V
Emitter-Base Voltage	V_{EBO}	12	V
Continuous Collector Current	Ι _C	500	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

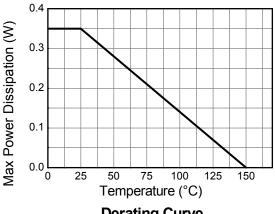
Characteristic		Symbol	Value	Unit	
Dower Dissination	(Note 5)	0	310	mW	
Power Dissipation	(Note 6)	P_{D}	350		
Thermal Desistance Junction to Ambient	(Note 5)	0	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	357	-C/VV	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C		

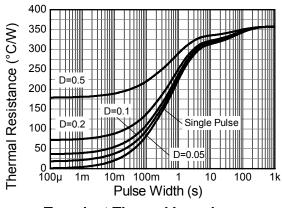
Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

 6. Same as note (5), except the device is mounted on 15 mm x 15mm 1oz copper.

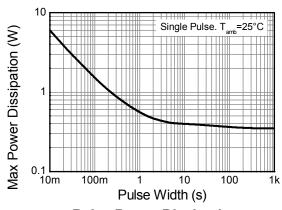
 7. Thermal resistance from junction to solder-point (at the end of the leads).





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	BV _{CBO}	80	_	_	V	$I_C = 100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CES}	80	_	_	V	$I_C = 100 \mu A, V_{BE} = 0$	
Emitter-Base Breakdown Voltage	BV_{EBO}	12	_	_	V	$I_E = 100 \mu A, I_C = 0$	
Collector cut-off current	I _{CBO}	_	_	100	nA	V _{CB} = 60V, I _E = 0	
Collector cut-on current	I _{CES}	_	_	500	nA	V _{CE} = 60V, V _{BE} = 0	
Emitter-base Cut-off Current	I _{EBO}	_	_	100	nA	V _{EB} = 10V, I _C = 0	
ON CHARACTERISTICS (Note 8)							
Static Forward Current Transfer Ratio	h _{FE}	10,000	_	_	_	I _C = 10mA, V _{CE} = 5V	
Static Folward Current Transfer Ratio		10,000				$I_C = 100 \text{mA}, V_{CE} = 5 \text{V}$	
Collector-Emitter Saturation Voltage	Vor. "		_	1.2	V	$I_C = 10 \text{mA}, I_B = 10 \mu \text{A}$	
Concetor-Emitter Cataration Voltage	V _{CE(sat)}			1.5	٧	$I_C = 100 \text{mA}, I_B = 100 \mu \text{A}$	
Base-Emitter Turn-On Voltage	$V_{BE(on)}$	_		2.0	V	$I_C = 100 \text{mA}, V_{CE} = 5 \text{V}$	
SMALL SIGNAL CHARACTERISTICS (Note 8)							
Current Gain-Bandwidth Product	f⊤	125	_	_	MHz	$I_C = 10$ mA, $V_{CE} = 5$ V,	
	•	1.20				f = 100MHz	
Output Capacitance	C_{obo}	_	8.0	_	pF	$V_{CB} = 10V, f = 1MHz, I_{E} = 0$	
Input Capacitance	C_{ibo}	_	15.0	_	pF	$V_{EB} = 0.5V, f = 1MHz, I_{C} = 0$	

Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

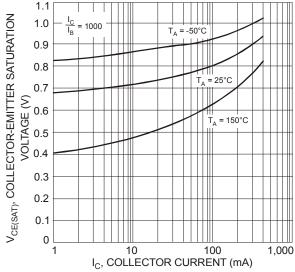
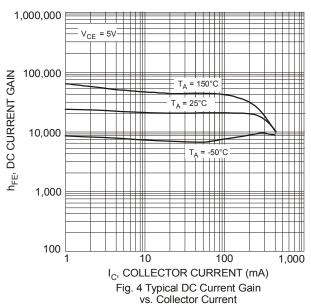


Fig. 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current



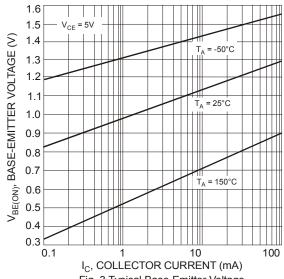


Fig. 3 Typical Base-Emitter Voltage vs. Collector Current

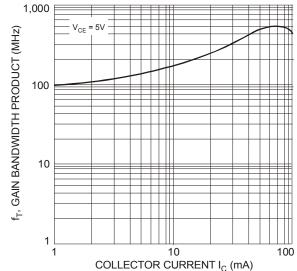
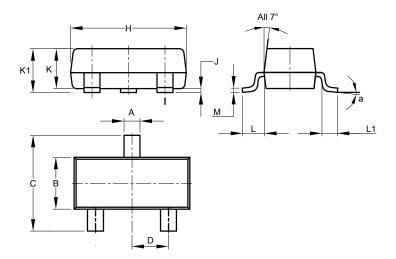


Fig. 5 Typical Gain Bandwidth Product vs. Collector Current



Package Outline Dimensions

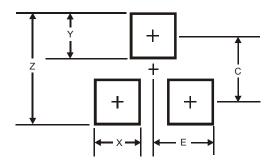
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Ι	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	a 8°						
All Dimensions in mm							

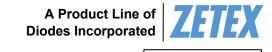
Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Υ	0.9
С	2.0
Е	1.35





IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2014, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: MMBTA28-7-F